

General Description

This product family offers state of the art performance. It is designed for high frequency applications where high efficiency and high reliability are required.

Features

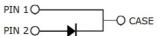
- Low conduction loss due to low VF
- Extremely low switching loss by tiny Qc
- Highly rugged due to better surge current
- Industrial standard quality and reliability

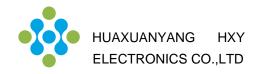
Applications

- UPS
- Power Inverter
- High performance SMPS
- Power factor correction

Ordering Part Number	Package	Qty(PCS)	
HIDK12G65C5	TO-263	800	





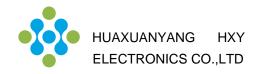


Maximum Ratings (at Tj = 25 °C, unless otherwise specified)

Parameter	Symbol	Value	Unit	
Repetitive Peak Reverse Voltage	Vrrm	650	V	
Surge Peak Reverse Voltage	Vrsm	650	V	
DC Peak Reverse Voltage	VR	650	V	
Continuous Forward Current				
Tc = 25°C Tc = 135°C Tc = 160°C	lf	30 15 12	А	
Repetitive Peak Forward Surge Current $T_{C} = 25^{\circ}C, t_{p} = 10 \text{ms}, \text{Half Sine Pulse}$ $T_{C} = 110^{\circ}C, t_{p} = 10 \text{ms}, \text{Half Sine Pulse}$	lfrм	48 29	А	
Non-Repetitive Forward Surge Current $T_C = 25^{\circ}C, t_P = 10 \text{ms}, Half Sine Pulse }$ $T_C = 110^{\circ}C, t_P = 10 \text{ms}, Half Sine Pulse}$	Ігѕм	90 70	А	
i^2 dt value $T_C = 25^{\circ}C, t_p = 10 ms, Half Sine Pulse T_C = 110^{\circ}C, t_p = 10 ms, Half Sine Pulse$	∫ i²dt	40.5 24.3	A²s	
Power dissipation $Tc = 25^{\circ}C$ $Tc = 110^{\circ}C$	P _{tot}	92 40	W	
Operating junction Range	Tj	-55 to +175	°C	
Storage temperature Range	Tstg	-55 to +150	°C	

Thermal Resistance

Parameter	Symbol	Value	Unit
Thermal resistance, junction - case.	RthJC	1.62	°C/W



Electrical Characteristic (at Tj = 25 °C, unless otherwise specified)

Parameter	Symbol	Value			Unit	Test Condition
		min.	typ.	max.	Oill	rest Condition
Forward Voltage	VF				٧	I _F =12A
		-	1.35	1.55		T _j =25°C
		-	1.6	-		Tj=175°C
Reverse Current					μΑ	Vr=650V
	lR	-	-	50		T _j =25°C
		-	-	200		T _j =175°C
Total Capacitive Charge	Qc	-	27		nC	V _R =400V,T _j =25℃
				-		$Q_C = \int_0^{V_R} C(V) dV$
Total Capacitance	С				pF	Tj=25℃, f=1MHz
		-	561	-		V _R =0V
		-	55	-		Vr=200V
		-	43	-		V _R =400V

Characteristics Curve:

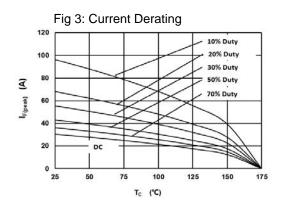
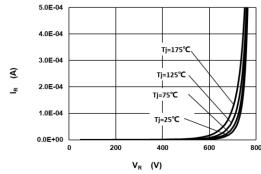


Fig 2: Reverse Characteristics



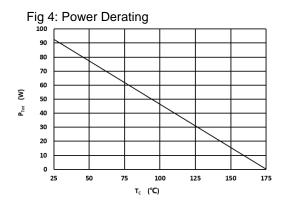


Fig 5: Capacitance vs. Reverse Voltage

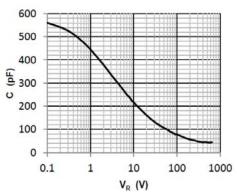


Fig 6: Reverse Charge vs. Reverse Voltage

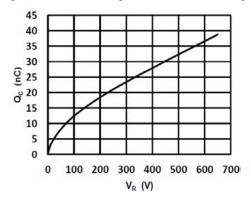


Fig 7: Typical Capacitance Stored Energy

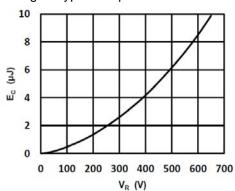
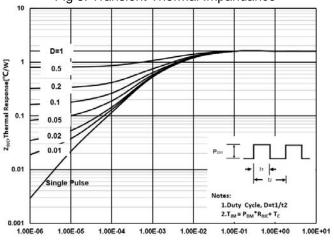


Fig 8: Transient Thermal Impandance

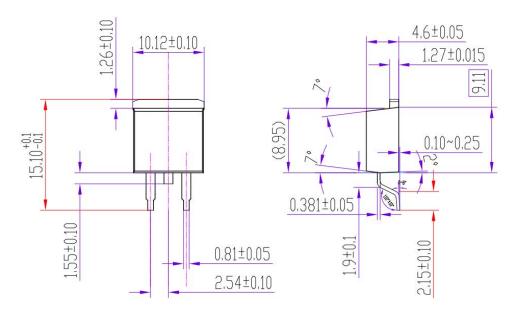


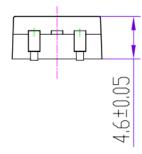
T , Rectangular Pulse Duration [sec]

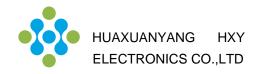


Package Dimensions

Package TO-263







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